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UG/2nd Sem/Elec./H/19 (Pr.)

2019

B.Sc.

## 2nd Semester Examination

## **ELECTRONICS** (Honours)

Paper - C3P

(Applied Physics Lab)

[Practical]

Full Marks: 20

Time: 3 Hours

The figures in the margin indicate full marks. Candidates are required to give their answers in their own words as far as practicable.

Answer any one question selecting it by a lucky draw.

 Measure the resistivity of a Si crystal using Fourprove method. Record the results at room temperature and six other temperatures upto 200°C. Plot resistivity of Si with temperature.

(Th + Ckt - 3, data recording - 8, Plot - 2, accuracy - 2)

Determine the value of Boltzman Constant from the study of forward characteristic of given P-N diode. Assume the material constant is equal to unity.

(Th+Ckt - 3, data recording - 8, plotting - 2, accuracy - 2)

 Determine the threshold voltage of the given LEDs operating in forward region. Calculate Planck's Constant from the threshold voltage. Perfrom the experiment for LEDs of four colours: Red, Green, Yellod and Blue.

(Th+Cket - 2, data - 2, accuracy - 1)

-4.

4. Write a programme using C / Mat lab / Sci lab to find the lowest energy eigen value for 1-D Schrodinger equation. Execute the programme to verify the result.

Prog. write - 3, Execution - 10, accuracy - 2)

- 5. Write a programme using C / Mat lab / Sci lab to plot tunelling probability as a function of barrier width and execute the programme.
- Write a programme using C / Mat Lab / Sci lab to plot Energy-Band-Diagram Corresponding to at least two different potential profile. Execute the programme.

(Programme - (2+2), Execution of the Prog. - (4+4), accuracy - 3).

## Distribution of Marks:

Experiment: 15

Laboratory Note Book: 02

Viva-voce: 03

Total 20 Marks